## Supplemental Declaration and Power of Attorney United States Patent Application

As a below named inventor, I hereby declare that;

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

## HIGH STRENGTH AND HIGH DUCTILITY MAGNESIUM ALLOY AND ITS PREPARATION METHOD

(check one)	is attached here		541 200	C 1 / C	
	applicable) wa	S. Application No. <u>10/582,</u>	541 on <u>June 9, 200</u>	6 and (if	
•		CT International Application	No. on	and (if	
		s amended under PCT Article		and (i)	
	иррисинсту жа	s amended under 1 C.1. Afficie	= 30 011		
amendment re	ferred to above. the duty to disclose in		ecification, including the claims, as ame entability as defined in Title 37. Code of		
application(s) country other	for patent or inventor's than the United States of	certificate, or §365(a) of any PCT of America listed in this Declaration	ode, §119(a)-(d) or §365(b) of any forci international application which design on. I have also identified below any for ing a filing date before that of the applic	ated at least one eign application	
priority is clai	<del></del>	No.			
Fereign/PCT Application No.		Country	Filing Date	Priority Claimed? (yes/no)	
200410020567.1		China	May 19, 2004	Yes	
international a each of the cla manner provid which is mate filing date of t	pplication designating tims of this application led by the first paragrap rial to patentability as d he prior application and	the United States of America lister is not disclosed in the prior United th of Title 35, United States Code,	§365(c) of any United States application d in this Declaration and, insofar as the d States application or PCT international. §112, I acknowledge the duty to disclost Regulations, §1.56 which became avail filing date of this application:	subject matter of il application in the isc information	
U.S.	Application No.	Filing Date	Status (patented/)	Status (patented/pending/abandoned/)	
		•		-	
1/1/4/	hereby appoint all atto	move of Smith Gambroll & Ruce	ell 11P who are listed under the HCDT	CO Character	

Number shown below as my/our attorneys to prosecute this application and to transact all business in the United States Patent and Trademark Office connected therewith, recognizing that the specific attorneys listed under that Customer Number may be changed from time to time at the sole discretion of Smith, Gambrell & Russell, LLP, and request that all correspondence be addressed to the address filed under the same USTPO Customer Number.

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Citizenship; China

Citizenship: China

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

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Signature: \_\_\_\_\_ Date: \_\_\_\_\_

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Full name of sole or first inventor:

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